Product data sheet

1. Product profile

1.1 General description

Triple high-voltage switching diodes, encapsulated in a SOT457 (SC-74) small Surface-Mounted Device (SMD) plastic package.

1.2 Features and benefits

- High switching speed: $t_{rr} \le 50$ ns
- Reverse voltage: V_R ≤ 200 V
- Repetitive peak reverse voltage: V_{RRM} ≤ 250 V
- Small SMD plastic package
- Low capacitance: C_d ≤ 5 pF
- AEC-Q101 qualified
- Repetitive peak forward current: I_{FRM} ≤ 1 A

1.3 Applications

- High-voltage switching in surface-mounted circuits
- Automotive
- Communication

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I _F	forward current		[1][2] _	-	200	mA
I _R	reverse current	V _R = 200 V	<u>[1]</u> _	25	100	nA
V_R	reverse voltage		-	-	200	V
t _{rr}	reverse recovery time		<u>[3]</u> _	16	50	ns

^[1] Pulse test: $t_D \le 300 \ \mu s; \ \delta \le 0.02$.



^[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[3] When switched from I_F = 30 mA to I_R = 30 mA; R_L = 100 Ω ; measured at I_R = 3 mA.

2. Pinning information

Table 2. Pinning

Pin Description Simplified outline Graphic symbol 1 cathode (diode 1) 2 cathode (diode 2) 3 cathode (diode 3) 4 anode (diode 3) 5 anode (diode 2) 6 anode (diode 1)	Table 2.	riiiiiig		
2 cathode (diode 2) 3 cathode (diode 3) 4 anode (diode 3) 5 anode (diode 2) 6 anode (diode 1)	Pin	Description	Simplified outline	Graphic symbol
2 cathode (diode 2) 3 cathode (diode 3) 4 anode (diode 3) 5 anode (diode 2) 6 anode (diode 1)	1	cathode (diode 1)		
4 anode (diode 3) 5 anode (diode 2) 6 anode (diode 1)	2	cathode (diode 2)	- 6 - 5 - 4	6 5 4
4 anode (diode 3) 5 anode (diode 2) 6 anode (diode 1) 1 2 3	3	cathode (diode 3)		
6 anode (diode 1)	4	anode (diode 3)		$\parallel \Psi \parallel \Psi \parallel \parallel$
a a loue (diode i)	5	anode (diode 2)		
	6	anode (diode 1)		1 2 3 006aab241

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BAS21VD	SC-74	plastic surface-mounted package; 6 leads	SOT457

4. Marking

Table 4. Marking codes

Type number	Marking code
BAS21VD	B5

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V _{RRM}	repetitive peak reverse voltage		-	250	V
V_R	reverse voltage		-	200	V
I _F	forward current		[1][3]	200	mA
I _{FRM}	repetitive peak forward current	$\begin{array}{l} t_p \leq 1 \text{ ms;} \\ \delta \leq 25 \text{ \%} \end{array}$	-	1	Α
I _{FSM}	non-repetitive peak	square wave	<u>[2]</u>		
	forward current	$t_{p} = 10 \ \mu s$	-	16	Α
		$t_p = 100 \ \mu s$	-	8	Α
		$t_p = 10 \text{ ms}$	-	2	Α

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 Table 5.
 Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per device	; one diode loaded				
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	[3] _	250	mW
			<u>[4]</u> _	295	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per device;	one diode loaded					
· · · · · · · · · · · · · · · · · · ·	thermal resistance from	in free air	<u>[1]</u> -	-	500	K/W
	junction to ambient		[2]	-	425	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		[3] _	-	140	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode	•					
V_{F}	forward voltage	I _F = 100 mA	-	-	1	V
		I _F = 200 mA	-	-	1.25	mV
I_R	reverse current	V _R = 200 V	<u>[1]</u> -	25	100	nA
		V _R = 200 V; T _j = 150 °C	-	-	100	μΑ
C_d	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	0.6	5	pF
t _{rr}	reverse recovery time		[2] _	16	50	ns

^[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

^[2] $T_i = 25$ °C prior to surge.

^[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

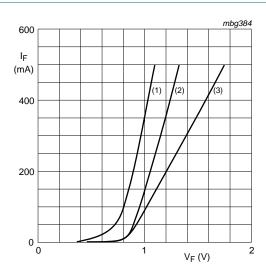
^{4]} Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

^[3] Soldering point of cathode tab.

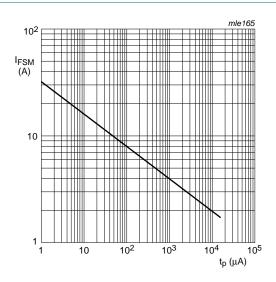
^[2] When switched from I_F = 30 mA to I_R = 30 mA; R_L = 100 Ω ; measured at I_R = 3 mA.

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- (1) $T_i = 150 \,^{\circ}\text{C}$; typical values
- (2) $T_i = 25$ °C; typical values
- (3) $T_i = 25 \,^{\circ}C$; maximum values

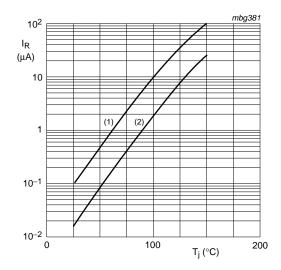
Fig 1. Forward current as a function of forward voltage



Based on square wave currents.

 $T_j = 25$ °C; prior to surge

Fig 2. Non-repetitive peak forward current as a function of pulse duration; maximum values



- (1) $V_R = V_{Rmax}$; maximum values
- (2) $V_R = V_{Rmax}$; typical values

Fig 3. Reverse current as a function of junction temperature

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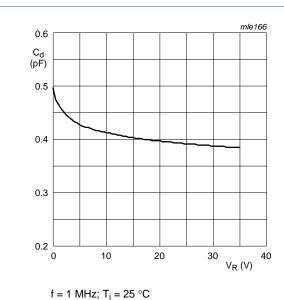
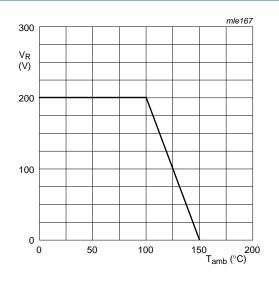
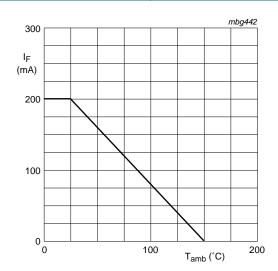


Fig 4. Diode capacitance as a function of reverse voltage; typical values



FR4 PCB, standard footprint

Fig 5. Reverse voltage as a function of ambient temperature; derating curve

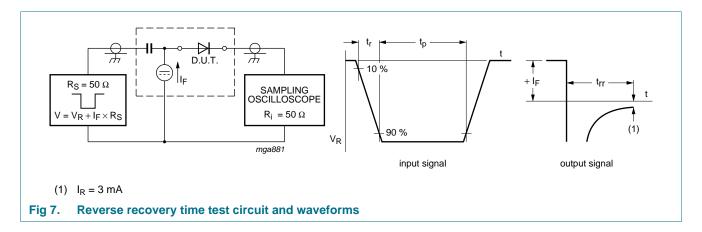


FR4 PCB, standard footprint

Fig 6. Forward current as a function of ambient temperature; derating curve

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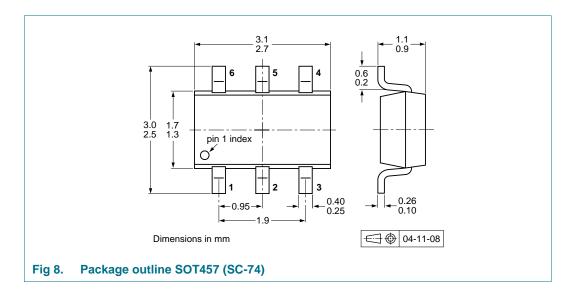
8. Test information



8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



High-voltage switching diodes

10. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description		Packing quantity	
				3000	10000
BAS21VD	SOT457	4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-135
		4 mm pitch, 8 mm tape and reel; T2	[3]	-125	-165

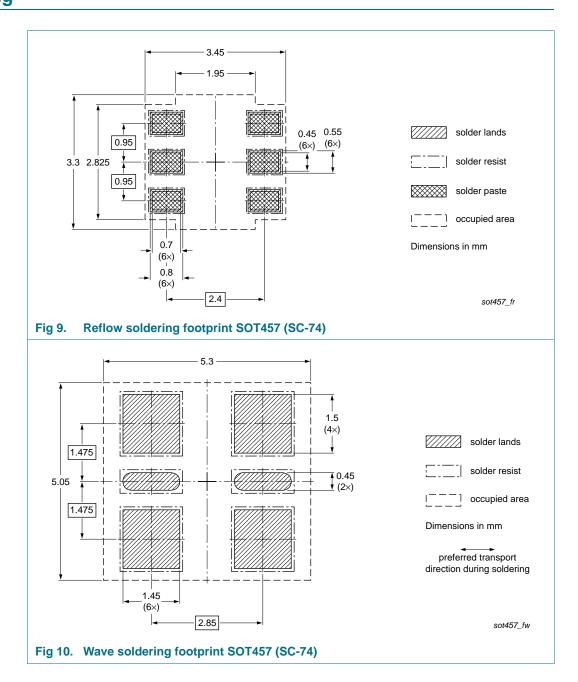
^[1] For further information and the availability of packing methods, see Section 14.

^[2] T1: normal taping

^[3] T2: reverse taping

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11. Soldering





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12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BAS21VD v.2	20110629	Product data sheet	-	BAS21VD v.1	
Modifications:		f this document has been NXP Semiconductors.	redesigned to comply w	ith the new identity	
	 Legal texts h 	ave been adapted to the n	ew company name whe	re appropriate.	
	 Section 1.4 "Quick reference data": added. 				
	 <u>Table 5</u>: added T_{amb}; updated P_{tot}. 				
	• <u>Table 6</u> : updated.				
	• Figure 1: upo	dated.			
	 Section 8.1 " 	Quality information": adde	d.		
	• Figure 8: rep	laced by minimized packa	ge outline drawing.		
	 Section 10 "F 	Packing information": adde	d.		
	 Section 11 "Soldering": added. 				
	 Section 13 "L 	<u>egal information"</u> : updated	d.		
BAS21VD v.1	20030703	Product data sheet	-	-	

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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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BAS21VD

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BAS21VD NXP Semiconductors

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